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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

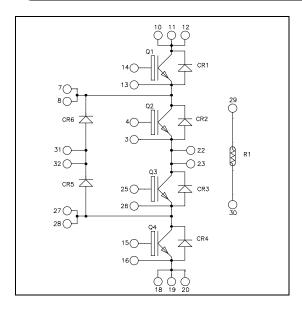


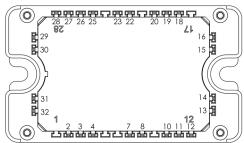




# Three level inverter High speed Trench + Field Stop IGBT4 Power Module

$$V_{CES} = 650V$$
  
 $I_{C} = 50A$  @  $Tc = 60$ °C





All multiple inputs and outputs must be shorted together; Example: 10/11/12; 7/8 ...

### **Application**

- Solar converter
- Uninterruptible Power Supplies

#### **Features**

- High speed Trench + Field Stop IGBT 4 Technology
  - Low voltage drop
  - Low leakage current
  - Low switching losses
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### **Benefits**

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

### All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

#### Absolute maximum ratings (per IGBT)

INSUIU	te maximum racings (per 13D1)			
Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Voltage		650	V
Ţ	Continuous Collector Current $\frac{T_C = 25^{\circ}C}{T_C = 60^{\circ}C}$	$=25^{\circ}C$	70	
$I_{\rm C}$		=60°C	50	Α
$I_{CM}$	Pulsed Collector Current T <sub>C</sub>	$=25^{\circ}C$	140	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_{D}$	Power Dissipation	·	175	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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### **Electrical Characteristics** (per IGBT)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 650V$				50	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C	1.4	1.85	2.3	V
		$I_C = 50A$ $T_j = 150^{\circ}C$	$T_j = 150$ °C		2.2		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 0.8 \text{ mA}$		4.2	5.1	5.6	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V$ , $V_{CE} = 0V$				150	nA

**Dynamic Characteristics** (per IGBT)

Symbol	Characteristic	Test Conditions	<b>S</b>	Min	Тур	Max	Unit
C <sub>ies</sub>	Input Capacitance	$V_{GE} = 0V$			3100		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$			116		рF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1MHz			90		•
$Q_{G}$	Gate charge	$V_{GE} = 15V, I_{C} = V_{CE} = 480V$	50A		315		nC
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (25°C)		19		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$			33		ns
$T_{d(off)}$	Turn-off Delay Time	$I_C = 50A$			197		
$T_{\rm f}$	Fall Time	$R_G = 7\Omega$			21		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_{C} = 50A$ $R_{G} = 7\Omega$			19		ns
$T_{\rm r}$	Rise Time				29		
T <sub>d(off)</sub>	Turn-off Delay Time				227		
$T_{\mathrm{f}}$	Fall Time				22		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 400V$ $I_{C} = 50A$ $R_{G} = 7\Omega$	$T_j = 150$ °C		1.2		mJ
E <sub>off</sub>	Turn off Energy		$T_j = 150$ °C		1		1113
$I_{sc}$	Short Circuit data	$V_{GE} \le 15V ; V_{Bu}$ $t_p \le 5\mu s ; T_j = 15$			350		A
$R_{thJC}$	Junction to Case Thermal Resistance	_				0.85	°C/W

### Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage					650	V
$I_{RM}$	Reverse Leakage Current	$V_R = 650V$				50	μΑ
$I_F$	DC Forward Current		$Tc = 25^{\circ}C$		50		A
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 50A$	$T_i = 25^{\circ}C$	1.6 2	2	V	
V F	Diode I of ward Voltage	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		v
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C		100		ns
ι <sub>rr</sub>	Reverse Recovery Time		$T_{j} = 150^{\circ}C$		150		113
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25$ °C		2.6		μС
Qrr	Reverse Recovery Charge		$T_{j} = 150^{\circ}C$		5.4		μС
$E_{rr}$	Reverse Recovery Energy		$T_j = 25^{\circ}C$		0.6		mJ
∟rr	Reverse Recovery Energy		$T_{\rm j} = 150^{\circ}{\rm C}$		1.2		1113
$R_{thJC}$	Junction to Case Thermal Resistance					1.42	°C/W



### $Temperature \ sensor \ NTC \ (\text{see application note APT0406 on www.microsemi.com}). \\$

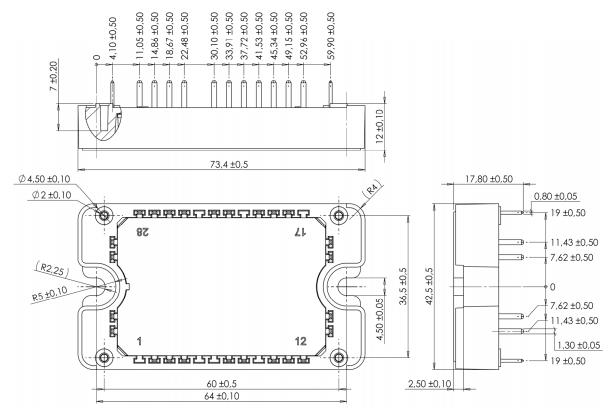
Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	esistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		$T_C=100$ °C		4		%

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_T: \text{ Thermistor value at T}$$

#### Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
$T_{J}$	Operating junction temperature range			-40	175	
$T_{JOP}$	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
$T_{STG}$	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

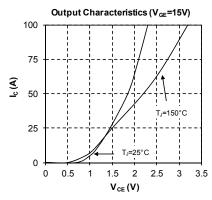
#### Package outline (dimensions in mm)

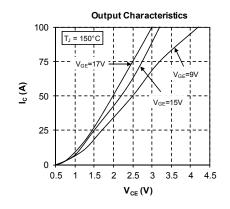


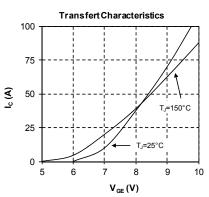
See application note 1906 - Mounting Instructions for SP3F Power Modules on www.microsemi.com

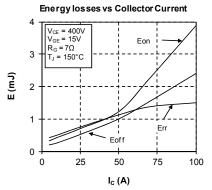


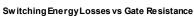
### Typical performance curve

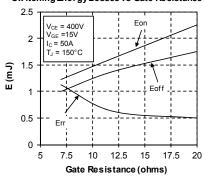


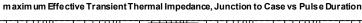


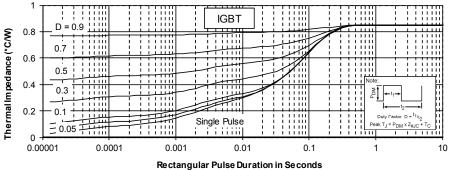








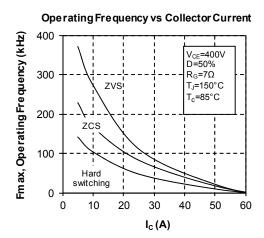


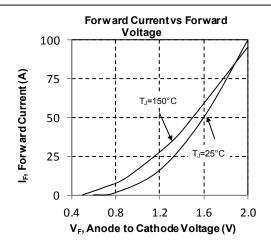


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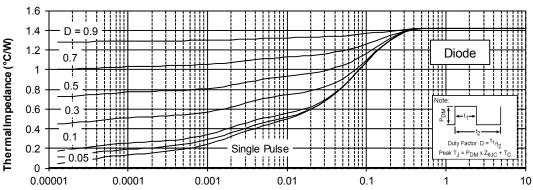
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Rectangular Pulse Duration in Seconds



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